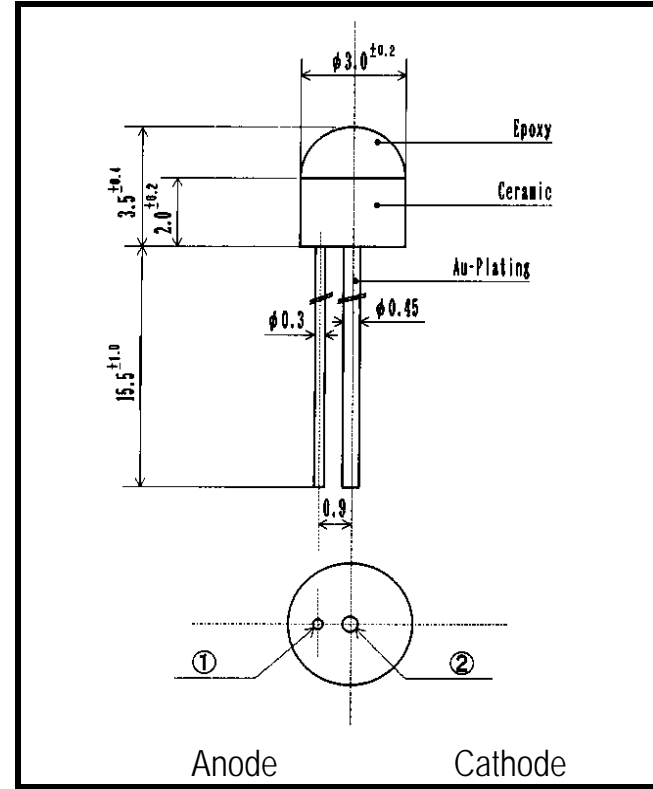


PDC141M3B

Photo Diode



- FEATURES**
- High Reliability
 - Very High Light Current
 - Linearity of L vs I_{sc}
 - Compact
- APPLICATIONS**
- Optical Switches
 - Optical Sensors
 - Optical Detectors

1. ABSOLUTE MAXIMUM RATINGS (Ta=25 °C)

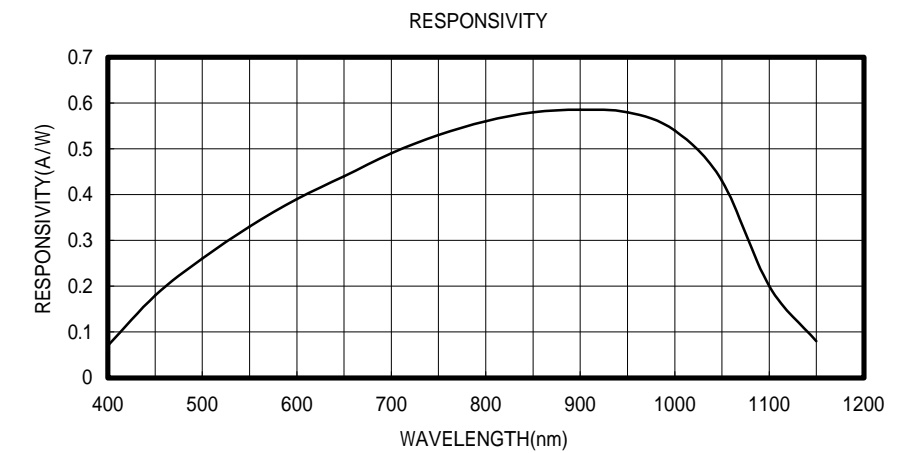
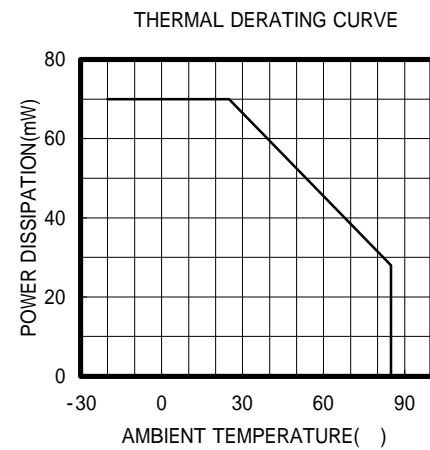
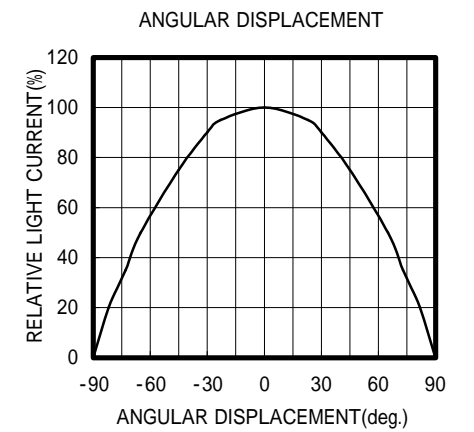
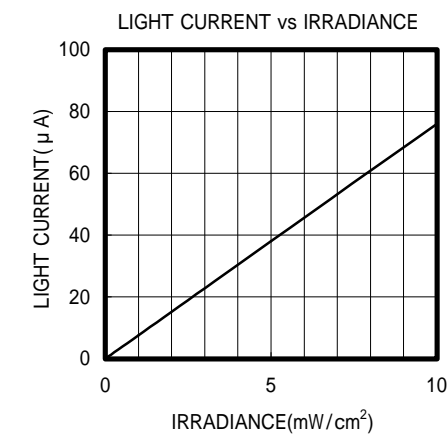
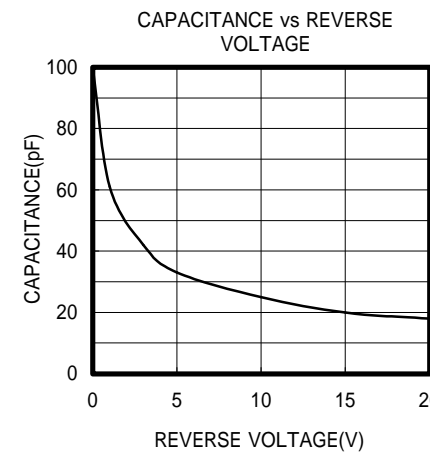
ITEM	SYMBOL	RATINGS	UNIT
Reverse Voltage	VR	20	V
Power Dissipation	PD	70	mW
Operating Temp.	Topr	-20 TO 85	
Storage Temp.	Tstg	-30 TO 100	
Junction Temp.	Tj	100	
Lead Soldering Temp.*1	Tls	260	

*1:Time 5 Sec max,Position:Up to 3mm from the body

2. ELECTRICAL & OPTICAL CHARACTERISTICS (Ta=25 °C)

ITEM	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Open Circuit Voltage	Voc	Ee=5mW/cm ²		0.35		V
Light Current	IL	VR=10V,Ee=5mW/cm ²		38		μA
Dark Current	ID	VR=10V		0.5	5	nA
Curve Factor	CF	Ee=5mW/cm ²	0.55			-
Spectral Sensitivity				400 ~ 1100		nm
Peak Sensitivity Wave Length	p			950		nm
Angular Response				±65		deg
Switching time (Rise Time)	Tr	RL=50 ,Vr=0V			2	μS
Switching time (Fall Time)	Tf	RL=50 ,Vr=0V			2	μS
Junction Capacitance	Cj	at 1MHz V=0V		100	130	pF

Color temperature=2870°K Standard Tungsten Lump



OPTRANS

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